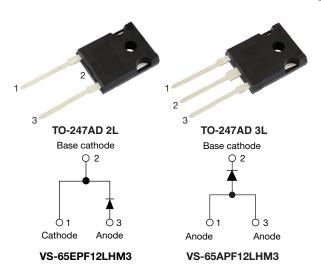
VS-65EPF12LHM3, VS-65APF12LHM3

Vishay Semiconductors

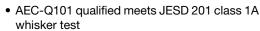
Fast Soft Recovery Rectifier Diode, 65 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	65 A				
V _R	1200 V				
V _F at I _F	1.42 V				
I _{FSM}	830 A				
t _{rr}	95 ns				
T _J max.	150 °C				
Package	TO-247AD 2L, TO-247AD 3L				
Circuit configuration	Single				
Snap factor	0.6				

FEATURES

- Very low forward voltage drop
- · Glass passivated pellet chip junction





- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage, and short reverse recovery time.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	65	А			
V _{RRM}		1200	V			
I _{FSM}		830	А			
t _{rr}	1 A, 100 A/μs	95	ns			
V _F	30 A, T _J = 25 °C	1.20	V			
TJ		-40 to +150	°C			

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-65EPF12LHM3	1200	1300	16
VS-65APF12LHM3	1200	1300	16



VS-65EPF12LHM3, VS-65APF12LHM3

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 113 °C, 180° conduction half sine wave	65		
Maximum peak one cycle non-repetitive surge current	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	700	Α	
		10 ms sine pulse, no voltage reapplied	830		
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	2450	A ² s	
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	3460	A-S	
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	34 600	A ² √s	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum forward voltage drop	V _{FM}	65 A, T _J = 25 °C		1.42	V
Forward slope resistance	r _t	T _J = 150 °C		4.6	mΩ
Threshold voltage	V _{F(TO)}			0.9	V
Maximum rayaraa laakaga ayrrant	1	T _J = 25 °C	V_{B} = rated V_{BBM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	VR = rated VRRM	16	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	Is at 60 Asis	480	ns	I _{FM} t
Reverse recovery current	I _{rr}	I _F at 60 A _{pk} 25 A/μs	8	А	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	2.7	μC	dir/ dt Q _{rr}
Snap factor	S	Typical	0.6		I I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resist unction to case	ance,	R_{thJC}	DC operation	0.25	
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.25	
Approximate weight				6	g
Approximate weight				0.21	OZ.
Mauratic a taurus minimum				6 (5)	kgf ⋅ cm
Mounting torque maxim	maximum			12 (10)	(lbf ⋅ in)
Madra da ta			Case style TO-247AD 2L	65EPF	12LH
Marking device			Case style TO-247AD 3L	65APF	12LH

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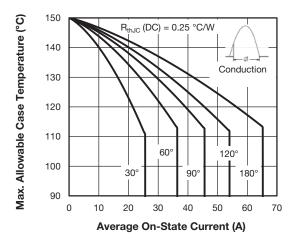


Fig. 1 - Current Rating Characteristics

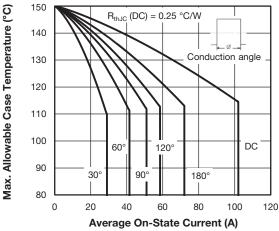


Fig. 2 - Current Rating Characteristics

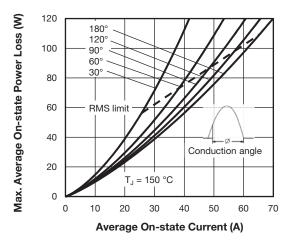


Fig. 3 - Forward Power Loss Characteristics

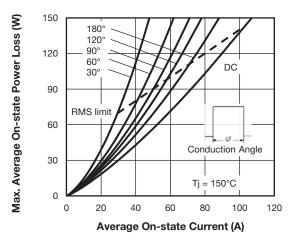


Fig. 4 - Forward Power Loss Characteristics

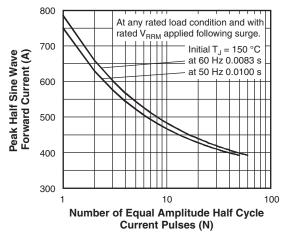


Fig. 5 - Maximum Non-Repetitive Surge Current

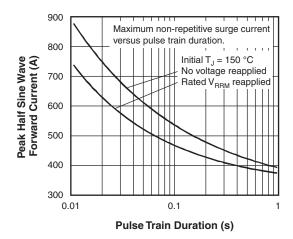


Fig. 6 - Maximum Non-Repetitive Surge Current

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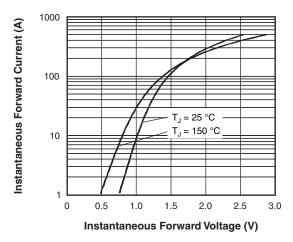


Fig. 7 - Forward Voltage Drop Characteristics

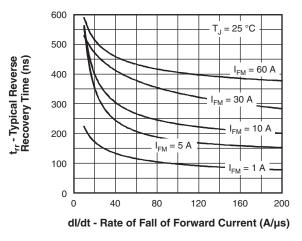


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

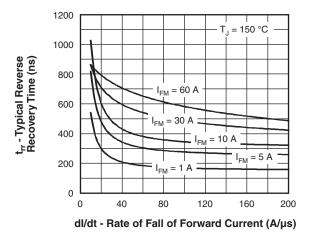


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

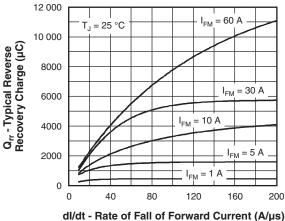


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

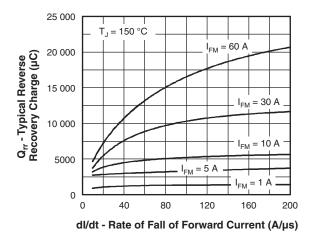


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

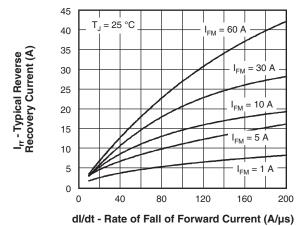


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

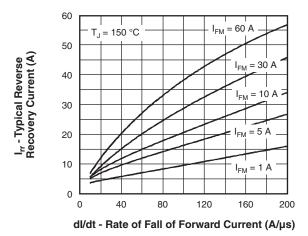


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

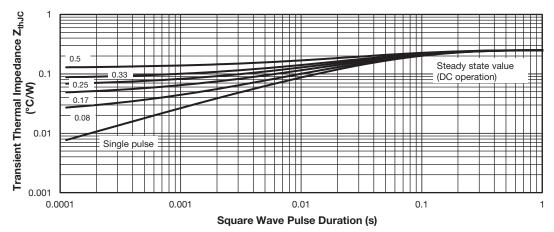


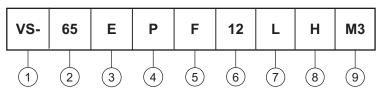
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-65EPF12LHM3, VS-65APF12LHM3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (65 = 65 A)

3 - Circuit configuration:

E = single, 2 pins

A = single, 3 pins

4 - Package:

5

i ackage.

P = TO-247AD

Type of silicon:

F = fast recovery rectifier

7 - L = long leads

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-65EPF12LHM3	25	500	Antistatic plastic tubes		
VS-65APF12LHM3	25	500	Antistatic plastic tubes		

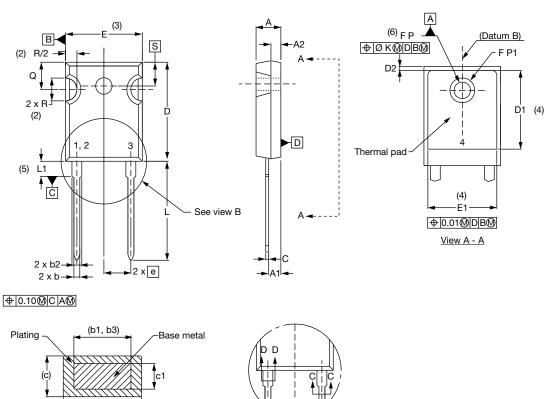
LINKS TO RELATED DOCUMENTS			
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536	
Dimensions -	TO-247AD 3L	www.vishay.com/doc?95626	
Dort marking information	TO-247AD 2L	www.vishay.com/doc?95648	
Part marking information -	TO-247AD 3L	www.vishay.com/doc?95007	



Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIMETERS		INCHES		NOTES
STWIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	5.46 BSC 0.215 BSC			
ØK	0.254		0.0	10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	5.51 BSC 0.217 BSC			
	•		•	•	

Notes

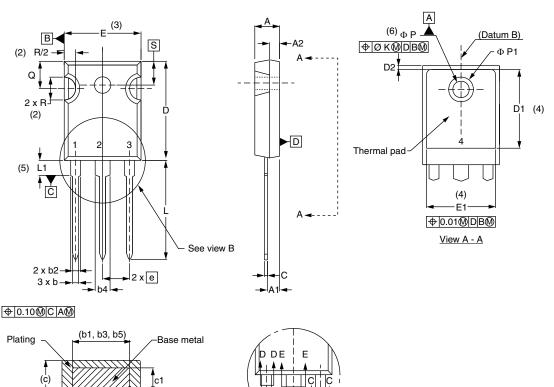
- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

Section C - C, D - D, E - E						
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• •			0.050			

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b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØΚ	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
		<u> </u>	<u> </u>	<u> </u>	

Notes

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- (2) Contour of slot optional
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- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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